

0.5 A ultra low V_F MEGA Schottky barrier rectifier in leadless ultra small SOD882 package

Rev. 03 — 15 January 2010

Product data sheet

1. Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier diode with an integrated guard ring for stress protection encapsulated in a SOD882 leadless ultra small plastic package.

1.2 Features

- Forward current: 0.5 A
- Reverse voltage: 20 V
- Ultra low forward voltage
- Leadless ultra small plastic package
- Power dissipation comparable to SOT23

1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits
- Low voltage rectification
- High efficiency DC-to-DC conversion
- Low power consumption applications

1.4 Quick reference data

Table 1.	Quick reference data			
Symbol	Parameter	Value	Unit	
I _F	forward current	0.5	А	
V _R	reverse voltage	20	V	



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2. Pinning information

Table 2.	Discrete pinning		
Pin	Description	Simplified outline	Symbol
1	cathode	[1]	
2	anode	1 D 2 Bottom view	1 🛃 2 sym001
		Top view 001aaa332	

[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering	g information		
Type number	Package		
	Name	Description	Version
PMEG2005AEL	-	leadless ultra small plastic package; 2 terminals; body 1.0 \times 0.6 \times 0.5 mm	SOD882

4. Marking

Table 4. Marking	
Type number	Marking code
PMEG2005AEL	F2

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _R	continuous reverse voltage		-	20	V
l _F	continuous forward current		-	0.5	А
I _{FRM}	repetitive peak forward current	$t_p \leq 1 \text{ ms; } \delta \leq 0.25$	-	2.5	А
I _{FSM}	non-repetitive peak forward current	t = 8 ms square wave	-	3	А
Tj	junction temperature		<u>[1]</u> _	150	°C
T _{amb}	operating ambient temperature		<u>[1]</u> –65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

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[1] For Schottky barrier diodes thermal run-away has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and I_{F(AV)} rating will be available on request.

6. Thermal characteristics

Table 6.	Thermal characteristics			
Symbol	Parameter	Conditions	Value	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	<u>[1][2]</u> 500	K/W

- [1] Refer to SOD882 standard mounting conditions (footprint), FR4 with 60 µm copper strip line.
- [2] For Schottky barrier diodes thermal run-away has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and $I_{F(AV)}$ rating will be available on request.

7. Characteristics

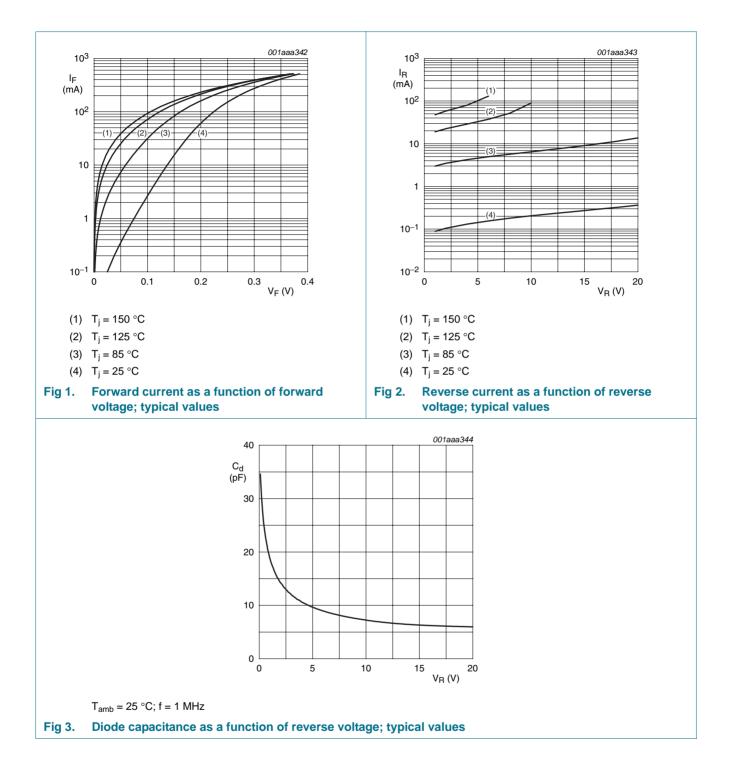
Table 7.Characteristics

 $T_{amb} = 25 \$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Тур	Max	Unit
V _F	continuous forward	see Figure 1;			
	voltage	I _F = 0.1 mA	25	60	mV
		I _F = 1 mA	75	110	mV
		I _F = 10 mA	135	190	mV
		I _F = 100 mA	220	290	mV
		I _F = 500 mA	375	440	mV
I _R	continuous reverse	see Figure 2; [1]			
	current	V _R = 10 V	210	600	μA
		V _R = 20 V	370	1500	μA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; see <u>Figure 3</u>	19	25	pF

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

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8. Package outline

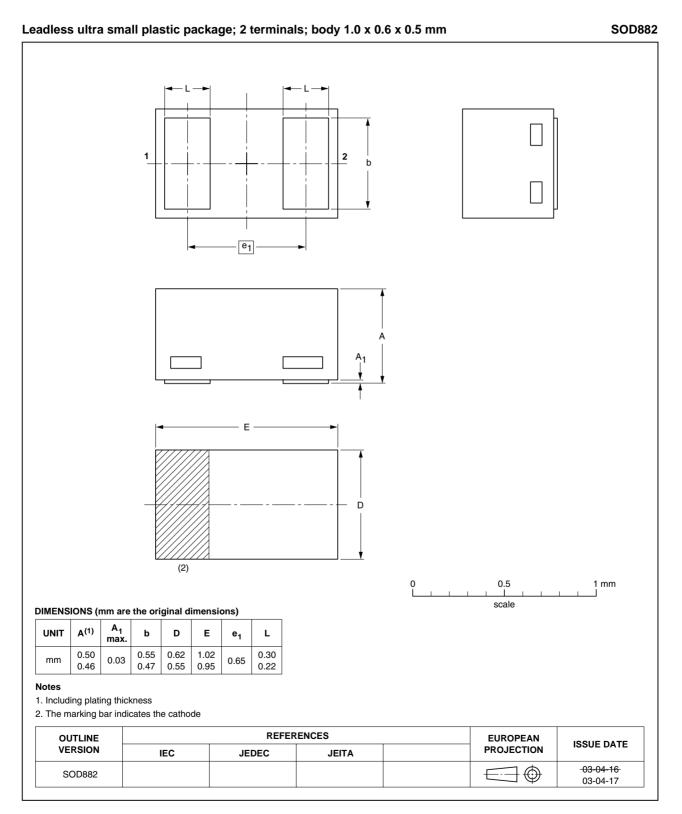


Fig 4. Package outline

PMEG2005AEL_3

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9. Revision history

Table 8. Revision his	story			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG2005AEL_3	20100115	Product data	-	PMEG2005AEL_2
Modifications:		eet was changed to reflect w legal definitions and disc		e NXP Semiconductors, rere made to the technical
PMEG2005AEL_2	20040427	Product data	-	PMEG2005AEL_1
PMEG2005AEL_1	20040419	Product data	-	-

10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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